

# Bias Resistor Transistor

## PNP Silicon Surface Mount Transistor with Monolithic Bias Resistor Network

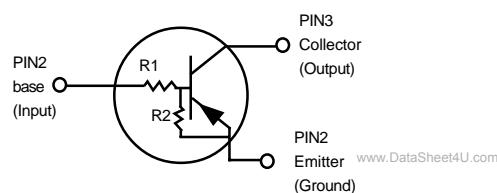
This new series of digital transistors is designed to replace a single device and its external resistor bias network. The BRT (Bias Resistor Transistor) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space. The device is housed in the SC-59 package which is designed for low power surface mount applications.

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- The SC-59 package can be soldered using wave or reflow.

The modified gull-winged leads absorb thermal stress during soldering eliminating the possibility of damage to the die.

- Available in 8 mm embossed tape and reel

Use the Device Number to order the 7 inch/3000 unit reel.



**MUN2111RT1  
MUN2112RT1  
MUN2113RT1  
MUN2114RT1  
MUN2115RT1  
MUN2116RT1  
MUN2130RT1  
MUN2131RT1  
MUN2132RT1  
MUN2133RT1  
MUN2134RT1**

**PNP SILICON  
BIAS RESISTOR  
TRANSISTOR**



**CASE 318-03 , STYLE 1  
( SC - 59 )**

### MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	50	Vdc
Collector-Emitter Voltage	$V_{CEO}$	50	Vdc
Collector Current	$I_C$	100	mAdc
Total Power Dissipation @ $T_A = 25^\circ\text{C}$ <sup>(1)</sup>	$P_D$	200	mW
Derate above $25^\circ\text{C}$		1.6	$\text{mW}/^\circ\text{C}$

### THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal Resistance — Junction-to-Ambient (surface mounted)	$R_{\theta JA}$	625	$^\circ\text{C}/\text{W}$
Operating and Storage Temperature Range	$T_J, T_{stg}$	-65 to +150	$^\circ\text{C}$
Maximum Temperature for Soldering Purposes	$T_L$	260	$^\circ\text{C}$
Time in Solder Bath		10	Sec

### DEVICE MARKING AND RESISTOR VALUES

Device	Marking	R1 (K)	R2 (K)
MUN2111RT1	6A	10	10
MUN2112RT1	6B	22	22
MUN2113RT1	6C	47	47
MUN2114RT1	6D	10	47
MUN2115RT1 <sup>(2)</sup>	6E	10	$\infty$
MUN2116RT1 <sup>(2)</sup>	6F	4.7	$\infty$
MUN2130RT1 <sup>(2)</sup>	6G	1.0	1.0
MUN2131RT1 <sup>(2)</sup>	6H	2.2	2.2
MUN2132RT1 <sup>(2)</sup>	6J	4.7	4.7
MUN2133RT1 <sup>(2)</sup>	6K	4.7	47
MUN2134RT1 <sup>(2)</sup>	6L	22	47

1. Device mounted on a FR-4 glass epoxy printed circuit board using the minimum recommended footprint.

2. New devices. Updated curves to follow in subsequent data sheets.

**MUN2111RT1 SERIES**
**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)**

Characteristic	Symbol	Min	Typ	Max	Unit
<b>OFF CHARACTERISTICS</b>					
Collector-Base Cutoff Current (V <sub>CB</sub> =50V, I <sub>E</sub> = 0)	I <sub>CBO</sub>	-	-	100	nAdc
Collector-Emitter Cutoff Current (V <sub>CE</sub> = 50 V, I <sub>B</sub> = 0)	I <sub>CEO</sub>	-	-	500	nAdc
Emitter-Base Cutoff Current (V <sub>EB</sub> = 6.0 V, I <sub>C</sub> = 0)	I <sub>EBO</sub>	-	-	0.5	mAdc
MUN2111RT1		-	-	0.2	
MUN2112RT1		-	-	0.1	
MUN2113RT1		-	-	0.2	
MUN2114RT1		-	-	0.9	
MUN2115RT1		-	-	1.9	
MUN2116RT1		-	-	4.3	
MUN2130RT1		-	-	2.3	
MUN2131RT1		-	-	1.5	
MUN2132RT1		-	-	0.18	
MUN2133RT1		-	-	0.13	
Collector-Base Breakdown Voltage (I <sub>C</sub> = 10 μA, I <sub>E</sub> = 0)	V <sub>(BR)CBO</sub>	50	-	-	Vdc
Collector-Emitter Breakdown Voltage <sup>(3)</sup> (I <sub>C</sub> =2.0mA, I <sub>B</sub> =0)	V <sub>(BR)CEO</sub>	50	-	-	Vdc
<b>ON CHARACTERISTICS<sup>(3)</sup></b>					
DC Current Gain (V <sub>CE</sub> = 10 V, I <sub>C</sub> = 5.0 mA)	MUN2111RT1	h <sub>FE</sub>	35	60	-
	MUN2112RT1		60	100	-
	MUN2113RT1		80	140	-
	MUN2114RT1		80	140	-
	MUN2115RT1		160	250	-
	MUN2116RT1		160	250	-
	MUN2130RT1		3.0	5.0	-
	MUN2131RT1		8.0	15	-
	MUN2132RT1		15	27	-
	MUN2133RT1		80	140	-
	MUN2134RT1		80	130	-
Collector-Emitter Saturation Voltage (I <sub>C</sub> =10mA, I <sub>E</sub> =0.3mA) (I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0.3 mA)	V <sub>CE(sat)</sub>				Vdc
MUN2111RT1 MUN2112RT1 MUN2113RT1 MUN2114RT1 MUN2115RT1 MUN2130RT1		-	-	0.25	
(I <sub>C</sub> = 10 mA, I <sub>B</sub> = 5.0 mA)	MUN2131RT1		-	-	0.25
(I <sub>C</sub> = 10 mA, I <sub>B</sub> = 1.0 mA)	MUN2116RT1 MUN2132RT1 MUN2134RT1		-	-	0.25
Output Voltage (on) (V <sub>CC</sub> =5.0V, V <sub>B</sub> =2.5V, R <sub>L</sub> =1.0kΩ)	V <sub>OL</sub>				Vdc
MUN2111RT1 MUN2112RT1 MUN2114RT1 MUN2115RT1 MUN2116RT1 MUN2130RT1 MUN2131RT1 MUN2132RT1 MUN2133RT1 MUN2134RT1		-	-	0.2	
(V <sub>CC</sub> =5.0V, V <sub>B</sub> =3.5V, R <sub>L</sub> = 1.0kΩ)	MUN2113RT1		-	-	0.2

3. Pulse Test: Pulse Width &lt; 300 ms, Duty Cycle &lt; 2.0%

**MUN2111RT1 SERIES**
**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ C$  unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Typ	Max	Unit
Output Voltage (off) ( $V_{CC} = 5.0V$ , $V_B = 0.5 V$ , $R_L = 1.0k\Omega$ ) ( $V_{CC} = 5.0V$ , $V_B = 0.050 V$ , $R_L = 1.0k\Omega$ ) ( $V_{CC} = 5.0V$ , $V_B = 0.25 V$ , $R_L = 1.0k\Omega$ )	$V_{OH}$	4.9	—	—	Vdc
MUN2130RT1					
MUN2115RT1					
MUN2116RT1					
MUN2131RT1					
MUN2132RT1					
Input Resistor	$R_1$	7.0	10	13	k $\Omega$
MUN2111RT1		15.4	22	28.6	
MUN2112RT1		32.9	47	61.1	
MUN2113RT1		7.0	10	13	
MUN2114RT1		7.0	10	13	
MUN2115RT1		3.3	4.7	6.1	
MUN2116RT1		0.7	1.0	1.3	
MUN2130RT1		1.5	2.2	2.9	
MUN2131RT1		3.3	4.7	6.1	
MUN2132RT1		3.3	4.7	6.1	
MUN2133RT1		15.4	22	28.6	
MUN2134RT1					
Resistor Ratio MUN2111RT1 MUN2112RT1 MUN2113RT1	$R_1/R_2$	0.8	1.0	1.2	
MUN2114RT1		0.17	0.21	0.25	
MUN2115RT1 MUN2116RT1		—	—	—	
MUN2130RT1 MUN2131RT1 MUN2132RT1		0.8	1.0	1.2	
MUN2133RT1		0.055	0.1	0.185	
MUN2134RT1		0.38	0.47	0.56	

## MUN2111RT1 SERIES

### TYPICAL ELECTRICAL CHARACTERISTICS MUN2111RT1

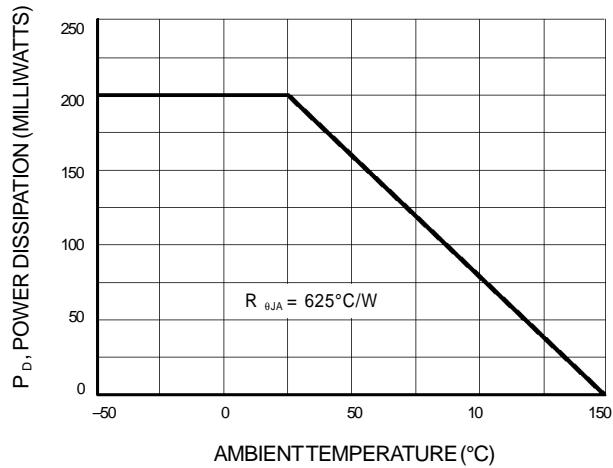


Figure 1. Derating Curve

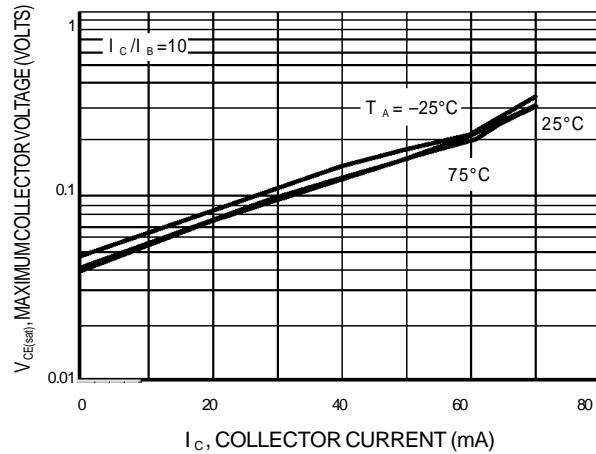


Figure 2.  $V_{CE(\text{sat})}$  versus  $I_C$

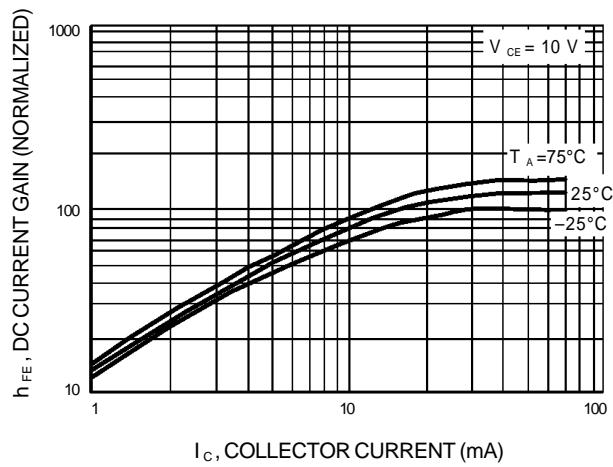


Figure 3. DC Current Gain

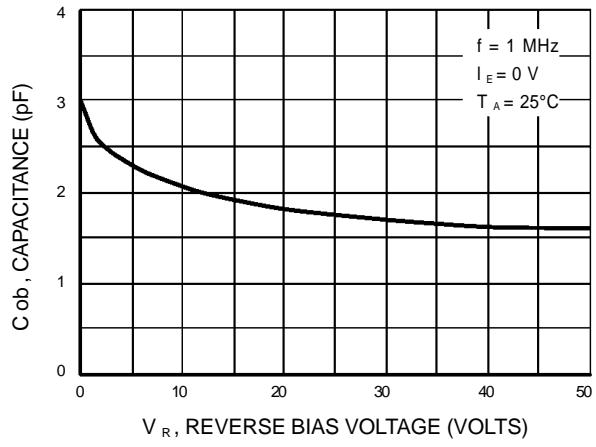


Figure 4. Output Capacitance

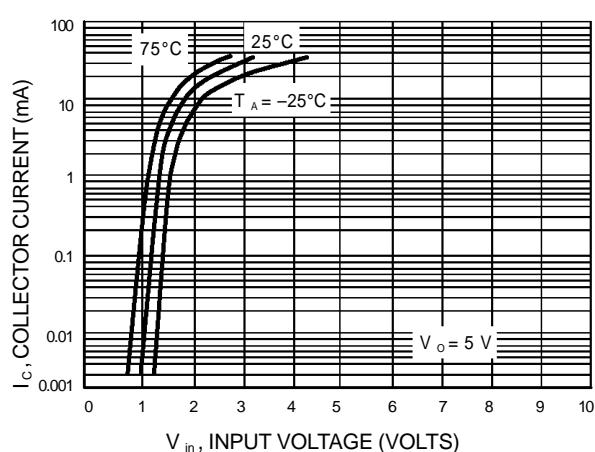


Figure 5. Output Current versus Input Voltage

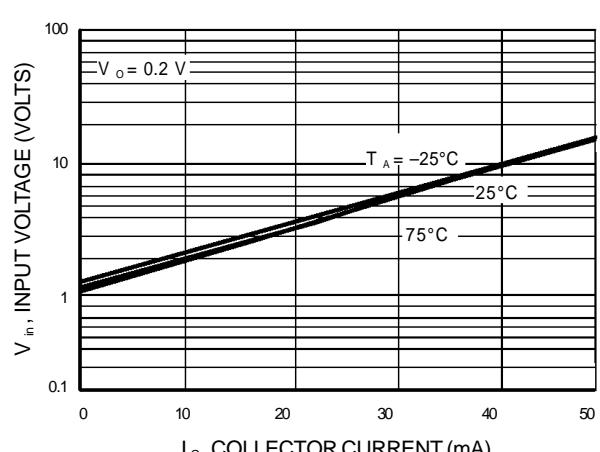
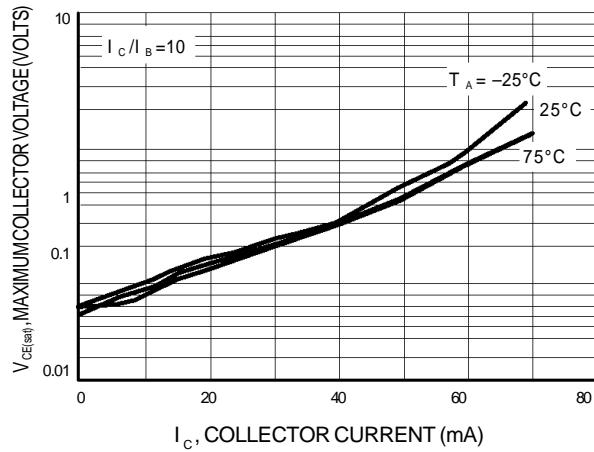


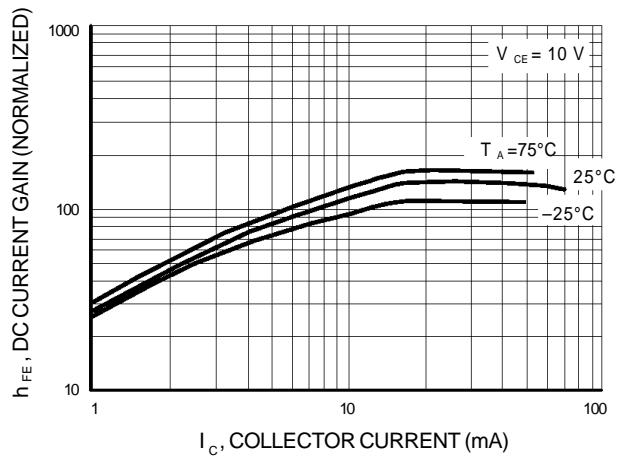
Figure 6. Input Voltage versus Output Current

## MUN2111RT1 SERIES

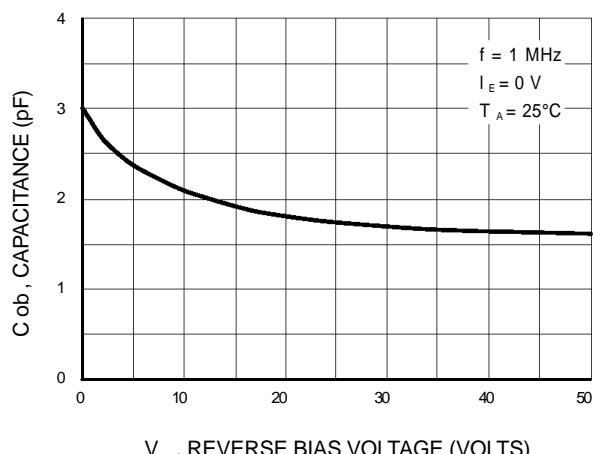
### TYPICAL ELECTRICAL CHARACTERISTICS MUN2111RT1



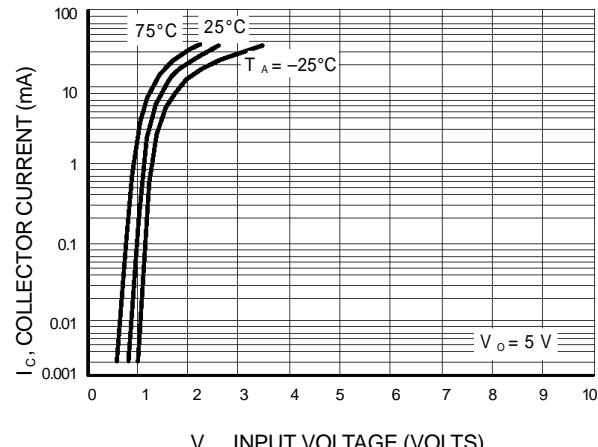
**Figure 7.  $V_{CE(sat)}$  versus  $I_c$**



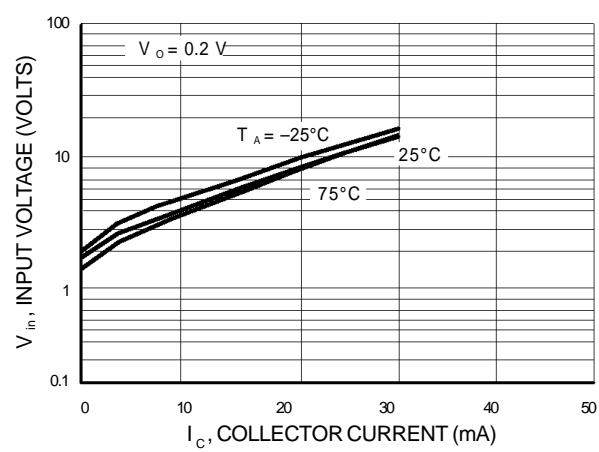
**Figure 8. DC Current Gain**



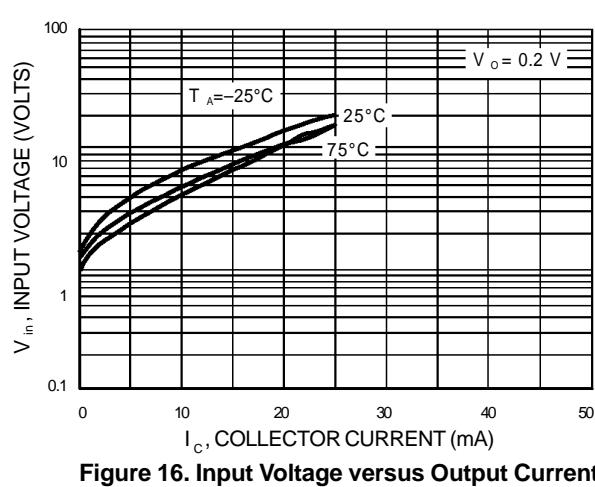
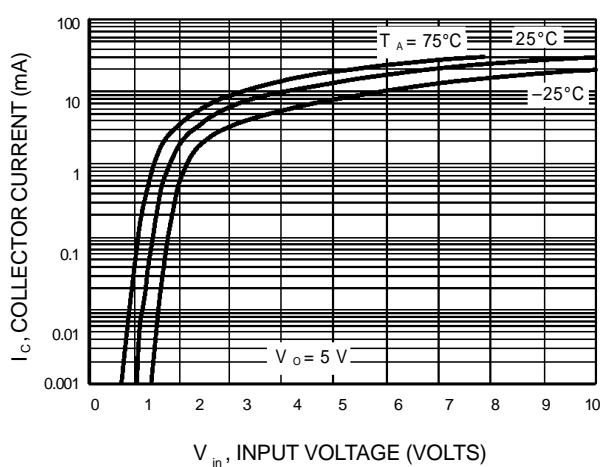
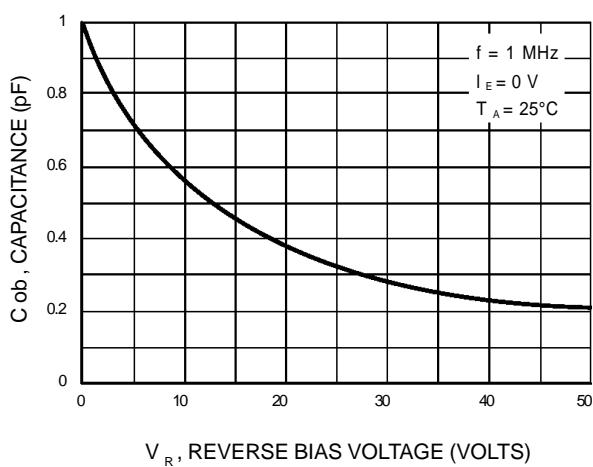
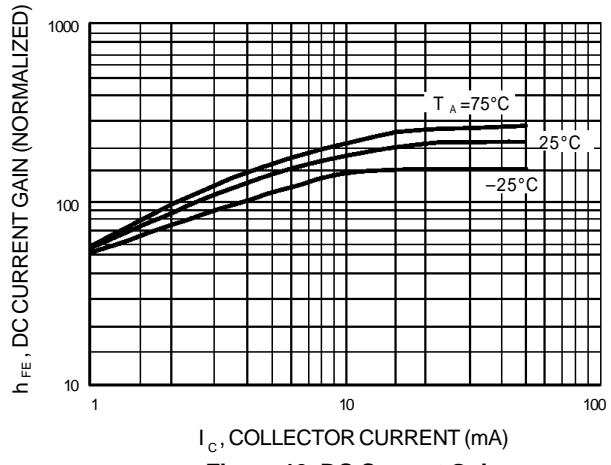
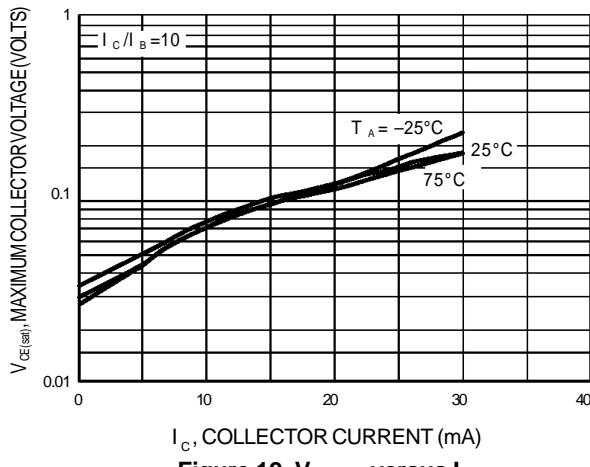
**Figure 9. Output Capacitance**

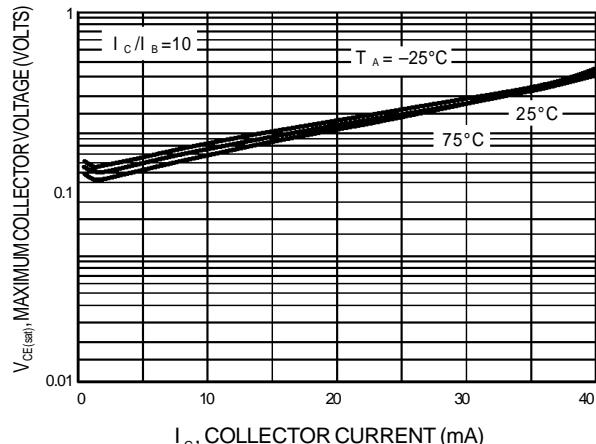
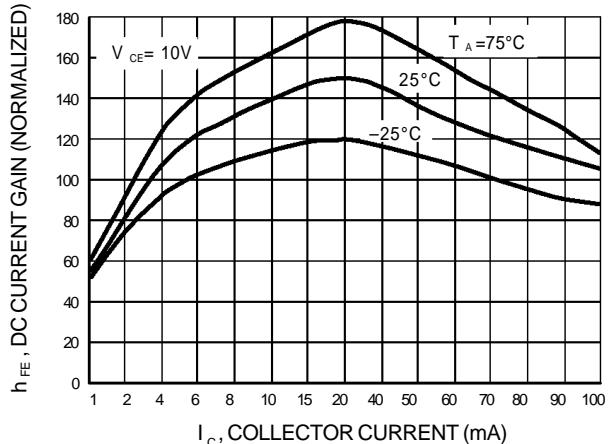
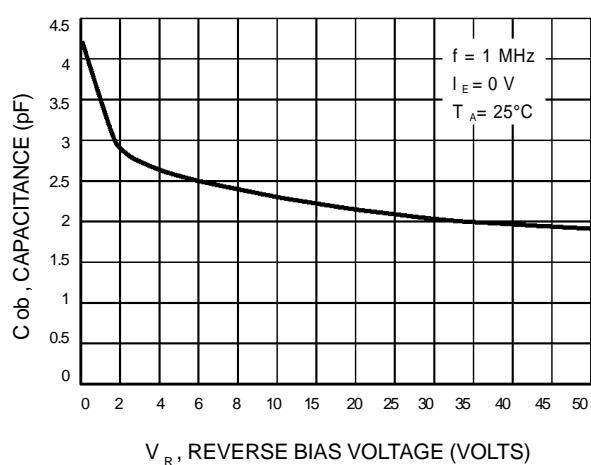
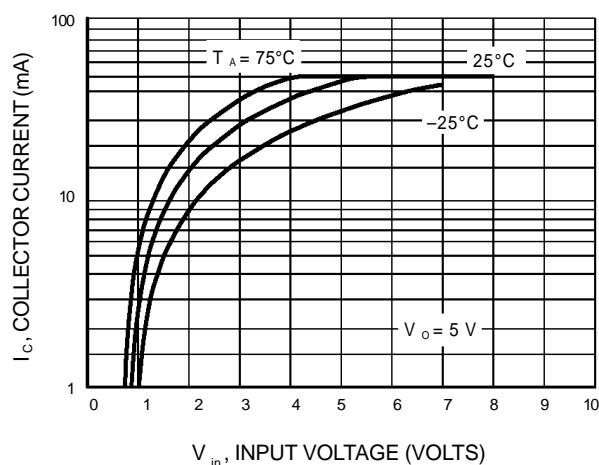
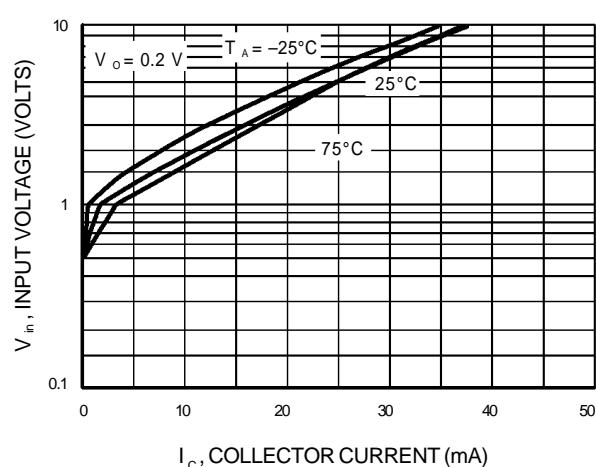
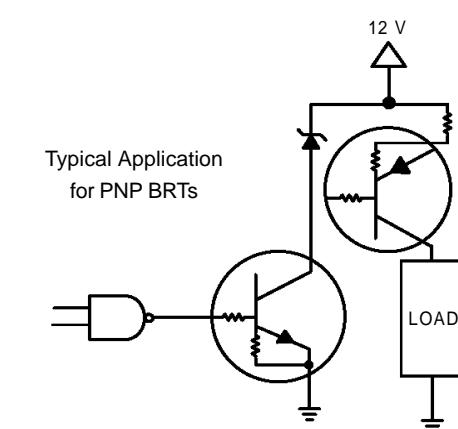


**Figure 10. Output Current versus Input Voltage**



**Figure 11. Input Voltage versus Output Current**

**MUN2111RT1 SERIES**
**TYPICAL ELECTRICAL CHARACTERISTICS  
MUN2113RT1**


**MUN2111RT1 SERIES**
**TYPICAL ELECTRICAL CHARACTERISTICS  
MUN2114RT1**

**Figure 17.  $V_{CE(\text{sat})}$  versus  $I_C$** 

**Figure 18. DC Current Gain**

**Figure 19. Output Capacitance**

**Figure 20. Output Current versus Input Voltage**

**Figure 21. Input Voltage versus Output Current**

**Figure 22. Inexpensive, Unregulated Current Source**